# VS-MBRB20...CTHM3, VS-MBR20...CT-1HM3

Vishay Semiconductors

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# High Performance Schottky Rectifier, 2 x 10 A

# D<sup>2</sup>PAK (TO-263AB) Base common common cathode cathode O 2 O 2 O 2 O 2 O 2 O 2 O 3 Anode cathode Anode Anode cathode Anode

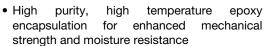
VS-MBR20 ...CT-1HM3

PRIMARY CHARACTERISTICS							
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA						
I <sub>F(AV)</sub> 2 x 10 A							
$V_{R}$	80 V, 90 V, 100 V						
V <sub>F</sub> at I <sub>F</sub>	0.70 V						
I <sub>RM</sub>	6 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
Diode variation	Common cathode						
E <sub>AS</sub>	24 mJ						

VS-MBRB20...CTHM3

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- Center tap D2PAK and TO-262 packages





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	^					
I <sub>FRM</sub>	T <sub>C</sub> = 133 °C (per leg)	20	_ A					
V <sub>RRM</sub>		80 to 100	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	Α					
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.70	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBRB2080CTHM3 VS-MBR2080CT-1HM3	VS-MBRB2090CTHM3 VS-MBR2090CT-1HM3	VS-MBRB20100CTHM3 VS-MBR20100CT-1HM3	UNITS			
Maximum DC reverse voltage	$V_R$	80	90	100	V			
Maximum working peak reverse voltage	$V_{RWM}$	60	90	100	V			



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ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average per leg	1	$T_C = 133 ^{\circ}\text{C}$ , rated $V_B$	10						
forward current per device	I <sub>F(AV)</sub>	IC = 133 G, rated V <sub>R</sub>	20						
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 133 °C	20						
Non repetitive peak ourge ourget		5 μs sine or Following any rated load condit and with rated V <sub>RRM</sub> applied	on 850	А					
Non-repetitive peak surge current	I <sub>FSM</sub>	Surge applied at rated load conditions half wave, single phase, 60 Hz	150						
Peak repetitive reverse surge current	I <sub>RRM</sub>	2.0 μs, 1.0 kHz	0.5						
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 2  \text{A},  L = 12  \text{mH}$	24	mJ					

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		10 A	T <sub>.1</sub> = 25 °C	0.80	V			
Maximum forward voltage drop	V (1)	20 A	1j = 25 C	0.95				
	V <sub>FM</sub> <sup>(1)</sup>	10 A	T <sub>.1</sub> = 125 °C	0.70				
		20 A	1j = 125 C	0.85				
Maximum instantaneous vouses surrent	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Dated DC valtage	0.10	mA			
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C	Rated DC voltage	6				
Threshold voltage	V <sub>F(TO)</sub>	T T mayimum		0.433	V			
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		15.8	mΩ			
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	400	pF				
Typical series inductance	L <sub>S</sub>	Measured from top of tern	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs			

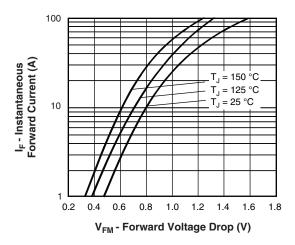
#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range		TJ		-55 to +150	°C	
Maximum storage tempe	erature range	T <sub>Stg</sub>		-65 to +150	-0	
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	2.0		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>	DC operation	50		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm (lbf · in)	
Mounting torque	maximum		Non-iubricated tiffeads	12 (10)		
				MBRB20	90CTH	
Marking device			Case style D <sup>2</sup> PAK (TO-263AB)	MBRB20	080CTH	
				MBRB20	100CTH	
				MBR209	0CT-1H	
			Case style TO-262AA	MBR208	0CT-1H	
				MBR2010	00CT-1H	

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100 10 I<sub>R</sub> - Reverse Current (mA) T<sub>J</sub> = 125 °C = 100 °C 0.1  $T_{J} = 75 \, ^{\circ}\text{C}$ T<sub>.1</sub> = 50 °C 0.01 T<sub>.1</sub> = 25 °C 0.001 0.0001 20 40 60 80 0 100 V<sub>R</sub> - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

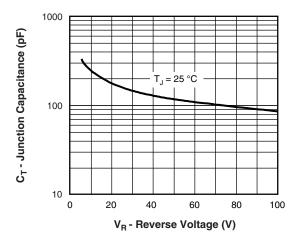


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

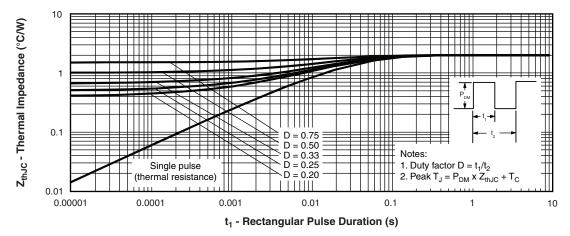


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

Allowable Case Temperature (°C)

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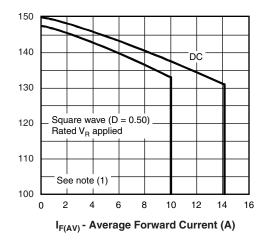


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

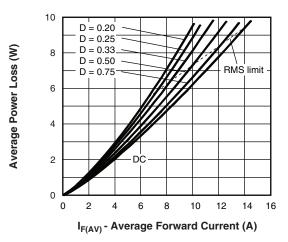


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

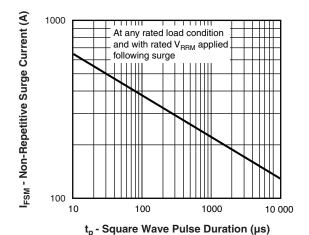


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

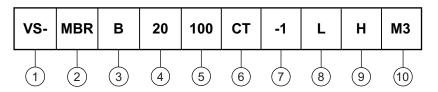
 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

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## **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Essential part number

• None = TO-262 7 = -1

4 - Current rating (20 = 20 A) 80 = 80 V 5 - Voltage ratings 90 = 90 V 100 = 100 V

6 - CT = common cathode

7 - • None = D<sup>2</sup>PAK **3** = B

• -1 = TO-262 **3** None

None = tube (50 pieces)

• L = tape and reel (left oriented - for D<sup>2</sup>PAK only)

• R = tape and reel (right oriented - for D<sup>2</sup>PAK only)

9 - • H = AEC-Q101 qualified

• M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MBRB2080CTHM3	50	1000	Antistatic plastic tube					
VS-MBRB2090CTHM3	50	1000	Antistatic plastic tube					
VS-MBRB20100CTHM3	50	1000	Antistatic plastic tube					
VS-MBRB2080CTLHM3	800	800	13" diameter reel					
VS-MBRB2090CTLHM3	800	800	13" diameter reel					
VS-MBRB20100CTLHM3	800	800	13" diameter reel					
VS-MBRB2080CTRHM3	800	800	13" diameter reel					
VS-MBRB2090CTRHM3	800	800	13" diameter reel					
VS-MBRB20100CTRHM3	800	800	13" diameter reel					
VS-MBRB2080CT-1HM3	50	1000	Antistatic plastic tube					
VS-MBRB2090CT-1HM3	50	1000	Antistatic plastic tube					
VS-MBRB20100CT-1HM3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95046				
Differsions	TO-262AA	www.vishay.com/doc?95419				
Dort marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95032				



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# D<sup>2</sup>PAK

## **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

## Notes

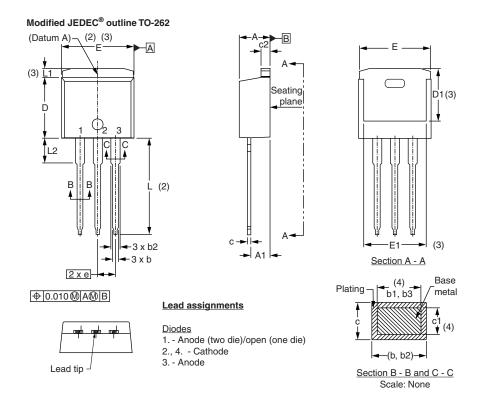
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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## **TO-262**

## **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	INCHES		
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.10	D BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.36	3.71	0.132	0.146		

## Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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